

MPQ3410 1.3A, 550kHz Synchronous Rectified Step-Up Converter AEC-Q100 Qualified

DESCRIPTION

The MPQ3410 is a highly efficient, synchronous, fixed frequency, current-mode step-up converter with output to input disconnect, inrush current limiting and internal soft-start. It includes an error amplifier, ramp generator, comparator, N-Channel switch and P-Channel synchronous rectified switch (which greatly improves efficiency). The output disconnect feature allows the output to be completely isolated from the input in shutdown mode.

The 550kHz switching frequency allows for smaller external components producing a compact solution for a wide range of load currents. The internal compensation and soft-start minimizes the external component count and limits the inrush current during startup. The MPQ3410 has integrated power MOSFET which can support up to 6V output and typical 1.3A switch current.

The MPQ3410 is offered in a thin SOT23-5 package.

FEATURES

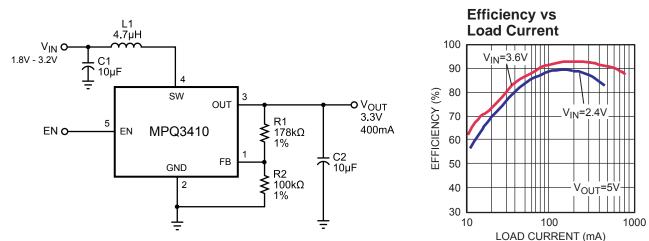
- Guaranteed Industrial/Automotive Temp Range Limits
- Over 90% Efficiency
- Output to Input Disconnect at Shutdown Mode
- Internal Synchronous Rectifier
- Inrush Current Limiting and Internal Soft-Start
- Internal Compensation
- 1.3A Typical Switch Current Limit
- 550kHz Fixed Switching Frequency
- Zero Current Shutdown Mode
- Thermal Shutdown
- 5-Pin TSOT-23 Package
- Available in AEC-Q100 Qualified Grade 1

APPLICATIONS

- MP3 Players
- Handheld Computers and PDAs
- Digital Still and Video Cameras
- External Modems
- Small LCD Displays

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TYPICAL APPLICATION

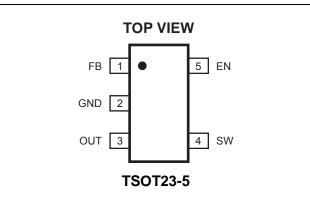
.0 www.MonolithicPower.com MPS Proprietary Information. Patent Protected. Unauthorized Photocopy and Duplication Prohibited. © 2015 MPS. All Rights Reserved.

ORDERING INFORMATION

Part Number	Package	Top Marking
MPQ3410DJ*	TSOT23-5	P3
MPQ3410DJ-AEC1**	TSOT23-5	P3

* For Tape & Reel, add suffix –Z (e.g. MP3410DJ–Z)
For RoHS compliant packaging, add suffix –LF (e.g. MP3410DJ–LF–Z)
** For Tape & Reel, add suffix –Z (e.g. MP3410DJ-AEC1–Z)
For RoHS compliant packaging, add suffix –LF (e.g. MP3410DJ-AEC1–LF–Z)

PACKAGE REFERENCE



ABSOLUTE MAXIMUM RATINGS (1)

All Pins	
Continuous Power Dissipation	$(T_A = +25^{\circ}C)^{(2)}$
Storage Temperature	-65°C to +150°C

Recommended Operating Conditions ⁽³⁾

Supply Voltage V _{IN}	1.8V to 6V
Output Voltage Vout	2.5V to 6V
Operating Junction Temp. (T _J)40°C to +125°C

Thermal Resistance ⁽⁴⁾ *θ_{JA} θ_{JC}* TSOT23-5 220 110...°C/W

Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature $T_J(MAX)$, the junction-toambient thermal resistance θ_{JA} , and the ambient temperature T_A . The maximum allowable continuous power dissipation at any ambient temperature is calculated by $P_D(MAX)=(T_J(MAX)-T_A)/\theta_{JA}$. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7 4-layer board.

ELECTRICAL CHARACTERISTICS

 $V_{EN} = V_{OUT} = 3.3V$, $T_J = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_J = 25^{\circ}C$.

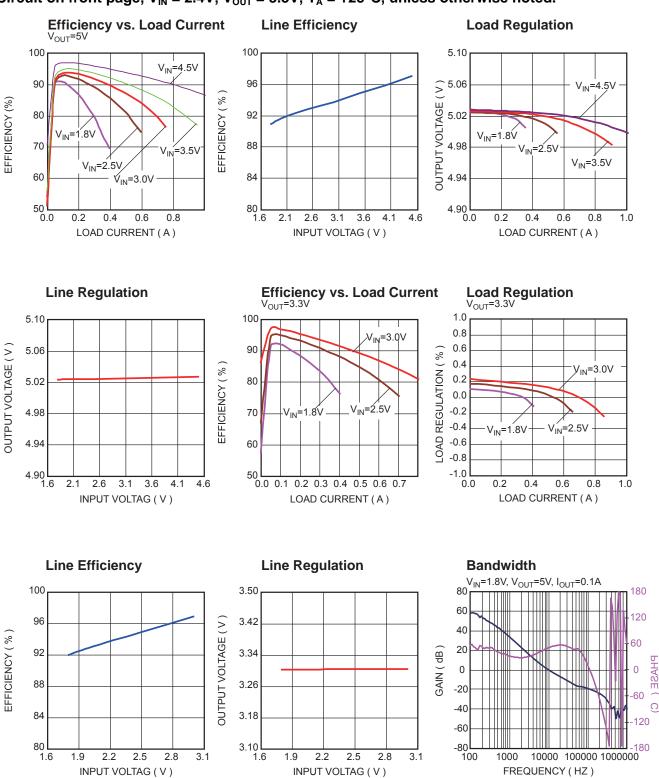
Parameter	Symbol	Condition	Condition		Тур	Max	Units
			T _J = 25°C	1.5	1.6	1.8	
Startup Supply Voltage	V_{ST}	$I_{LOAD} = 0mA$	T _J = -40°C to +125°C	1.4		1.8	V
		$R_{LOAD} = 50\Omega$			1.65		
Output Voltage Range	V _{OUT}			2.5		6.0	V
Supply Current (Shutdown)		V _{EN} = V _{OUT} =0V,	T _J = 25°C		0.15	0.5	μA
		$V_{SW} = 5V$	T_{J} = -40°C to +125°C			5	I.
Supply Current		V _{FB} = 1.3V			360		μA
Foodbook Voltago	V	T _J = 25°C		1.15	1.19	1.23	V
Feedback Voltage	V_{FB}	T _J = -40°C to +125°C		1.14		1.24	
Feedback Input Current		V _{FB} = 1.19V			50		nA
Quitabing Frequency	f _{sw}	T _J = 25°C		410	550	690	KHz
Switching Frequency		T _J = -40°C to +125°C		330		690	
Maximum Duty Cycle	D _{MAX}			80	90	95	%
EN Input Low Voltage						0.4	V
EN Input High Voltage		V _{IN} =1.8V V _{IN} =3.3V		1.05			V
(see Chart <u>EN high voltage</u> <u>vs Input</u> for details)				1.65			
		V _{IN} =5V		2.15			
EN Pull Down Resistor					1		MΩ
Low-Side On Resistance (5)	R _{ONLS}	V _{OUT} = 3.3V			300		mΩ
Low-Side Current Limit (5)	I _{LIM}				1.3		А
High-Side On Resistance (5)	R _{ONHS}	V _{OUT} = 3.3V			530	700	mΩ
Thermal Shutdown (5)					160		°C
Thermal Shutdown Hysteresis ⁽⁵⁾					30		°C

Note:

5) Guaranteed by design, not tested.

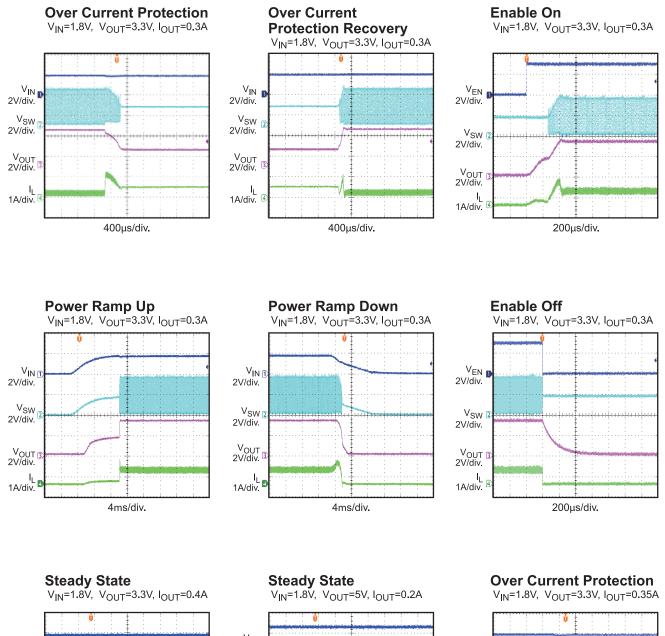
TYPICAL PERFORMANCE CHARACTERISTICS

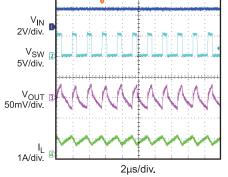
Circuit on front page, V_{IN} = 2.4V, V_{OUT} = 3.3V, T_A = +25°C, unless otherwise noted.

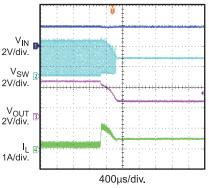


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Circuit on front page, $V_{IN} = 2.4V$, $V_{OUT} = 3.3V$, $T_A = +25^{\circ}C$, unless otherwise noted.







2µs/div.

VIN

2V/div

5V/div

V_{OUT} 50mV/div.

VSW

ار 1A/div

TYPICAL PERFORMANCE CHARACTERISTICS (continued) Circuit on front page, V_{IN} = 2.4V, V_{OUT} = 3.3V, T_A = +25°C, unless otherwise noted. IQ Current vs. TJ Feedback Voltage vs. TJ Switching Frequency vs. T_J 600 600 1.5 SWITCHING FREQUENCY (kHz) FEEDBACK VOLTAGE (V) 560 560 1.4 IQ CURRENT (µA) 520 520 1.3 1.2 480 480 440 1.1 440 1.0 400 400 -10 20 50 80 110 140 -40 -10 20 50 80 110 140 -40 -10 20 50 80 110 140 -40 JUNCTION TEMPERATURE (°C) JUNCTION TEMPERATURE (°C) JUNCTION TEMPERATURE (°C) Enable ON/OFF vs. TJ Current Limit vs. **Duty Cycle** 2.0 1.4 1.6 V_{EN} VOLTAGE (V) Enable ON CURRENT LIMIT (A) 1.2 1.2 1.0 0.8 Enable OFF 0.8 0.4 0.0 0.6 20 110 140 40 60 80 100 -10 20 50 80 0 -40 JUNCTION TEMPERATURE (°C) DUTY CYCLE (%) **Transient Response Transient Response** I_{LOAD} = 40mA to 400mA Step I_{LOAD} = 40mA to 400mA Step w/o Feed-Forward Capacitor with 220pF Feed-Forward Capacitor V_{OUT} AC V_{OUT} AC 100mV/div. 100mV/div. I_{LOAD} 0.2A/div. I_{LOAD} 0.2A/div. 400ms/div. 400ms/div.

PIN FUNCTIONS

Pin #	Name	Description
1	FB	Regulation Feedback Input. Connect to an external resistive voltage divider from the output to FB to set the output voltage.
2	GND	Ground.
3	OUT	Supply Input for the MPQ3410. Connect to the output of the converter.
4	SW	Output Switching Node. SW is the drain of the internal low-side N-Channel MOSFET and high-side P-Channel MOSFET. Connect the inductor to SW to complete the step-up converter.
5	EN	Regulator On/Off Control Input. A logic high input turns on the regulator. A logic low input (V _{EN} < 0.4V) puts the MPQ3410 into low current shutdown mode. EN Input High Voltage will shift upward for a higher V _{IN} . For a given V _{IN} , as long as the voltage applied at EN pin is equal to or higher than correspondent EN-High-min value specified in the EC table , the part can turn on normally.

ΠΠΙ

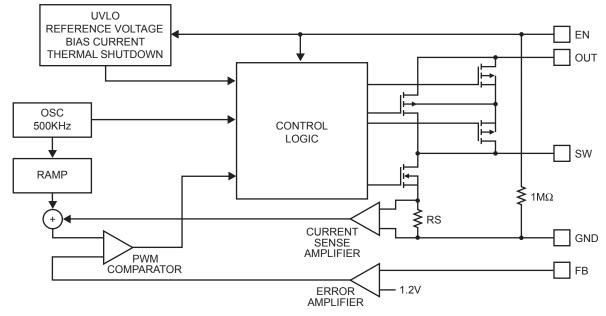


Figure 1—Functional Block Diagram

OPERATION

The MPQ3410 uses a 550kHz fixed-frequency, current-mode regulation architecture to regulate the output voltage. The MPQ3410 measures the output voltage through an external resistive voltage divider and compares that to the internal 1.2V reference to generate the error voltage. The current-mode regulator compares the error voltage to the inductor current to regulate the output voltage. The use of current-mode regulation improves transient response and control loop stability.

When the MPQ3410 is disabled (EN = Low), both power switches are off. The body of the P-Channel MOSFET connects to SW and there is no current path from SW to OUT. Therefore, the output voltage discharges to ground. When the MPQ3410 is enabled (EN = High), the body of the P-Channel MOSFET connects to OUT and forms a forward diode from SW to OUT. Thus the output voltage rises up toward the input voltage. When output voltage crosses 1.6V the MPQ3410 starts the controller and regulates the output voltage to the target value.

At the beginning of each cycle, the N-Channel MOSFET switch is turned on, forcing the inductor current to rise. The current at the

source of the switch is internally measured and converted to a voltage by the current sense amplifier. That voltage is compared to the error voltage. When the inductor current rises sufficiently, the PWM comparator turns off the switch, forcing the inductor current to the output capacitor through the internal P-Channel MOSFET rectifier, which forces the inductor current to decrease. The peak inductor current is controlled by the error voltage, which in turn is controlled by the output voltage. Thus the output voltage controls the inductor current to satisfy the load.

Soft-Start

The MPQ3410 includes a soft-start timer that limits the voltage at the error amplifier output during startup to prevent excessive current at the input. This prevents premature termination of the source voltage at startup due to inrush current. This also limits the inductor current at startup, forcing the input current to rise slowly to the amount required to regulate the output voltage during soft-start.

APPLICATION INFORMATION COMPONENT SELECTION

Setting the Output Voltage

Set the output voltage by selecting the resistive voltage divider ratio. The voltage divider drops the output voltage to the 1.19V feedback voltage. Use a $100k\Omega$ resistor for R2 of the voltage divider. Determine the high-side resistor R1 by the equation:

$$R1 = \frac{V_{OUT} - V_{FB}}{\left(\frac{V_{FB}}{R2}\right)}$$

Where V_{OUT} is the output voltage, V_{FB} is the 1.19V feedback voltage and R2=100k Ω .

Selecting the Input Capacitor

An input capacitor is required to supply the AC ripple current to the inductor, while limiting noise at the input source. Multi-layer ceramic capacitors are the best choice as they have extremely low ESR and are available in small footprints. Use an input capacitor value of 4.7μ F or greater. This capacitor must be placed physically close to the device.

Selecting the Output Capacitor

A single 4.7μ F to 10μ F ceramic capacitor usually provides sufficient output capacitance for most applications. Larger values up to 22μ F may be used to obtain extremely low output voltage ripple and improve transient response. The impedance of the ceramic capacitor at the switching frequency is dominated by the capacitance, and so the output voltage ripple is mostly independent of the ESR. The output voltage ripple V_{RIPPLE} is calculated as:

$$V_{RIPPLE} = \frac{I_{LOAD} (V_{OUT} - V_{IN})}{V_{OUT} \times C2 \times f_{SW}}$$

Where V_{IN} is the input voltage, I_{LOAD} is the load current, C2 is the capacitance of the output capacitor and f_{SW} is the 550kHz switching frequency.

Selecting the Inductor

The inductor is required to force the output voltage higher while being driven by the lower input voltage. A good rule for determining the inductance is to allow the peak-to-peak ripple current to be approximately 30%-50% of the maximum input current. Make sure that the peak inductor current is below the minimum current limit at the duty cycle used (to prevent loss of regulation due to the current limit variations).

Calculate the required inductance value L using the equations:

$$L = \frac{V_{IN} \times (V_{OUT} - V_{IN})}{V_{OUT} \times f_{SW} \times \Delta I}$$
$$I_{IN(MAX)} = \frac{V_{OUT} \times I_{LOAD(MAX)}}{V_{IN} \times \eta}$$
$$\Delta I = (30\% - 50\%)I_{IN(MAX)}$$

Where $I_{LOAD(MAX)}$ is the maximum load current, ΔI is the peak-to-peak inductor ripple current and η is efficiency. For the MPQ3410, typically, 4.7µH is recommended for most applications. Choose an inductor that does not saturate at the peak switch current as calculated above with additional margin to cover heavy load transients and extreme startup conditions.

Selecting the Feed-Forward Capacitor

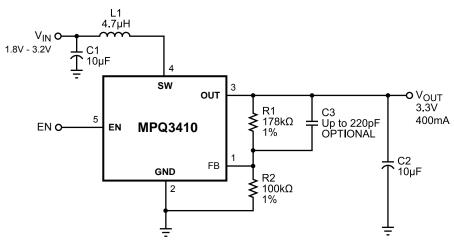
A feed-forward capacitor C3 in parallel with the high-side resistor R1 can be added to improve the output ripple at discontinuous conduction mode and the load transient response (see Figure 2). Up to 220pF for this capacitor is recommended for 3.3V output applications.

Selecting the Schottky Diode

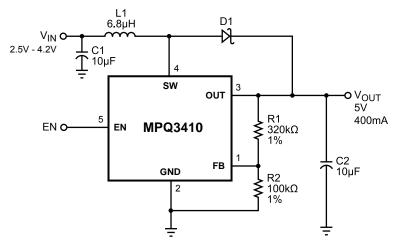
A Schottky diode D1 in parallel with the highside P-Channel MOSFET is necessary to clamp the SW node to a safe level for outputs of 4V or above. A 0.5A, 20V Schottky diode can be used for this purpose. See Figure 3.

LAYOUT CONSIDERATIONS

High frequency switching regulators require very careful layout for stable operation and low noise. All components must be placed as close to the IC as possible. All feedback components must be kept close to the FB pin to prevent noise injection on the FB pin trace. The ground return of C1 and C2 should be tied close to the GND pin. See the MPQ3410 demo board layout for reference.











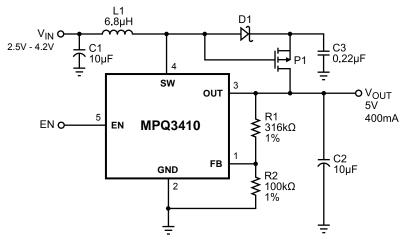


Figure 4—5V Typical Application Circuit with External Schottky Diode and Output Disconnect Required

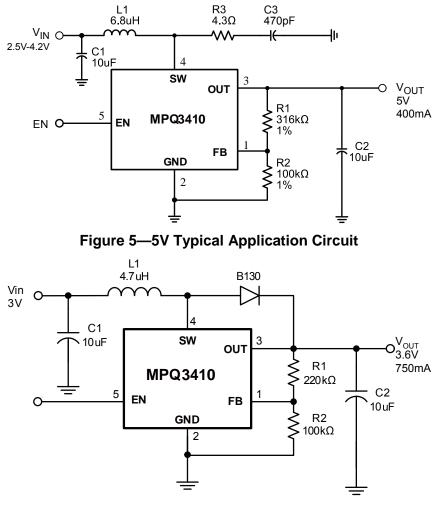
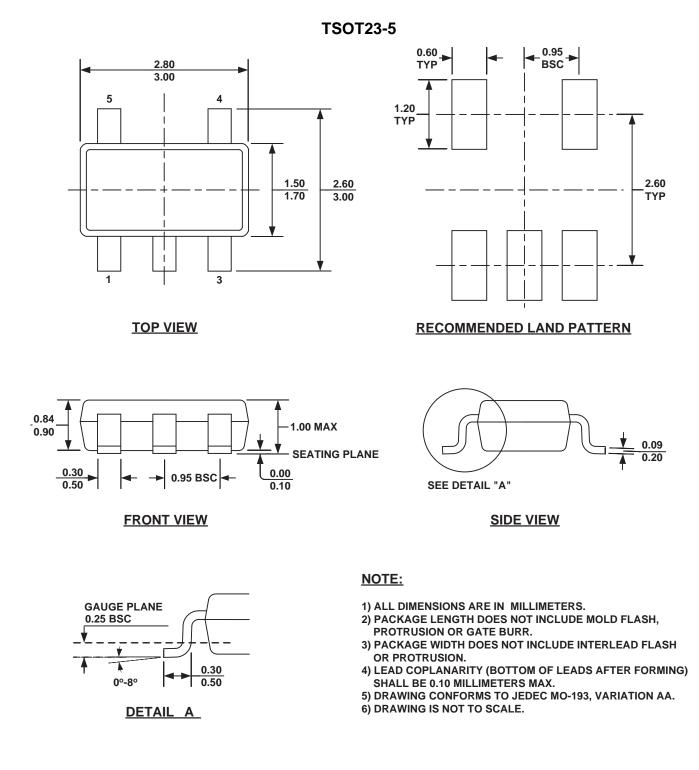


Figure 6—3V-3.8V/750mA Application

PACKAGE INFORMATION



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